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Docket No. 1232-4610US1

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s):

Kazutaka Yanagita et al.

Group Art Unit: 2

2812

Serial No.:

09/494,851

Examiner:

Stacy Whitmore

Filed:

February 1, 2000

For:

COMPOSITE MEMBER AND SEPARATING METHOD THEREFOR, BONDED SUBSTRATE STACK AND SEPARATING METHOD THEREFOR, TRANSFER METHOD FOR TRANSFER LAYER, AND SOI SUBSTRATE MANUFACTURING

**METHOD** 

## **INFORMATION DISCLOSURE STATEMENT**

Commissioner for Patents Washington, D.C. 20231

Sir:

This Information Disclosure Statement is filed in accordance with 37 C.F.R. §§1.56, 1.97 and 1.98. The items listed on Form PTO-1449, a copy of which is enclosed, are made of record to assist the Patent and Trademark Office in its examination of this application. The Examiner is respectfully requested to fully consider the items and to independently ascertain their teaching.

- 1. For each of the following items listed on the enclosed copy of Form PTO-1449 that is not in the English language, an English language translation of that item or a portion thereof or a concise explanation of the relevance of that item is enclosed:
- 2. For each of the following items listed on the enclosed copy of Form PTO-1449 that is not in the English language, a concise explanation of the relevance of that item is incorporated in the specification of the above-identified application.
- 3. Any copy of the items listed on the enclosed copy of Form PTO-1449 that is not enclosed with this Information Disclosure Statement was previously cited by or submitted to the Patent and Trademark Office in application Serial No. 09/494,851, filed February 1, 2000.

4.	$\boxtimes$	No fee is due under 37 C.F.R. §1.17(p) for this Information Disclosure Statement since it is being filed in compliance with:		
		$\boxtimes$	37 C.F.R. §1.97(b)(1), within three months of the filing date of a national application other than a CPA; or	
			37 C.F.R. §1.97(b)(2), within three months of the date of entry into the national stage as set forth in §1.491 in an international application; or	
			37 C.F.R. §1.97(b)(3), before the mailing date of a first Office action on the merits; or	
			37 C.F.R. §1.97(b)(4) before the mailing date of a first office action after the filing of an RCE under §1.114.	
5.		No fee is due under 37 C.F.R. §1.17(p) for this Information Disclosure Statement since it is being filed in compliance with 37 C.F.R. §1.97(c), after the period specified in paragraph 4 above but before the mailing date of a final action or a Notice of Allowance (where there has been no prior final action), and is accompanied by one of the certifications pursuant to 37 C.F.R. §1.97(e) set forth in paragraph 9 below.		
6.	it is being filed in compliance with paragraph 4 above but before the m		is due under 37 C.F.R. §1.17(p) for this Information Disclosure Statement since eing filed in compliance with 37 C.F.R. §1.97(c), after the period specified in raph 4 above but before the mailing date of a final action or a notice of ance (where there has been no prior final action):	
			A check in the amount of \$180.00 is enclosed in payment of the fee.	
			Charge the fee to Deposit Account No. <u>13-4500</u> , Order No A DUPLICATE COPY OF THIS SHEET IS ATTACHED.	
7.		A fee is due under 37 C.F.R. §1.17(p) for this Information Disclosure Statement since it is being filed in compliance with 37 C.F.R. §1.97(d), after the mailing date of a final action or a notice of allowance, whichever comes first, but before payment of the issue fee, and is accompanied by:		
			ne of the certifications pursuant to 37 C.F.R. §1.97(e) set forth in paragraph 9 elow; and	
			ne fee due under 37 C.F.R. §1.17(p) which is paid as set forth in paragraph 11	

8.		A fee is due under 37 C.F.R. §1.17(p) for this Information Disclosure Statement since it is being filed in compliance with:			
		a. 🗌	37 C.F.R. §1.313(b)(3) or §1.313(c)(1), after the issue fee has been paid and information cited in this Information Disclosure Statement may render at least one claim unpatentable and is accompanied by the attached Petition To Withdraw Application From Issue and fee pursuant to 37 C.F.R. §1.17(h);		
		b	37 C.F.R. §1.313(c)(2) or §1.313(c)(3), after the issue fee has been paid and information cited in this Information Disclosure Statement is to be considered in a Request for Continued Examination (RCE) or a Continuation application upon abandonment of the instant application and is accompanied by the attached Petition To Withdraw Application From Issue and fee pursuant to 37 C.F.R. §1.17(h).		
		c	The fees due under 37 C.F.R. §§1.17(h) and 1.17(p) are paid as set forth in paragraph 11 below.		
9.		I hereby certify that each item of information contained in this Information Disclos Statement was first cited in a communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of this Information Disclosure Statement.			
		filed h counte was kr	by certify that no item of information in the Information Disclosure Statement erewith was cited in a communication from a foreign patent office in a expart foreign application or, to my knowledge after making reasonable inquiry, nown to any individual designated in §1.56(c) more than three months prior to any of this Information Disclosure Statement.		
10.		This document is accompanied by _ a Search Report _ Communication which we cited in a corresponding _ PCT or _ Foreign counterpart application			
11.		A check in the amount of \$180.00 is enclosed in payment of the fees due under 37 C.F.R. §§1.17(h) and 1.17(p).			
		13-450	e the fees due under 37 C.F.R. §§1.17(h) and 1.17(p) to Deposit Account No. 00, Order No A DUPLICATE COPY OF THIS SHEET IS CHED.		

The Commissioner is hereby authorized to charge any additional fees which may be required for this Information Disclosure Statement, or credit any overpayment to Deposit Account No. <u>13-4500</u>, Order No. <u>1232-4610</u>. A DUPLICATE COPY OF THIS SHEET IS ATTACHED.

Respectfully submitted,

MORGAN & FINNEGAN, L.L.P.

Dated: February 21, 2002

Gerard E. Reinhardt Registration No. 43,041

Correspondence Address:

MORGAN & FINNEGAN, L.L.P. 345 Park Avenue New York, NY 10154-0053 (212) 758-4800 Telephone (212) 751-6849 Facsimile The Commissioner is hereby authorized to charge any additional fees which may be required for this Information Disclosure Statement, or credit any overpayment to Deposit Account No. 13-4500, Order No. 1232-4610. A DUPLICATE COPY OF THIS SHEET IS ATTACHED.

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## Attorney Docket: Serial No.: **FORM PTO-1449** 1232-4610US1 09/494,851 Applicant: **INFORMATION** Kazutaka Yanagita et al. DISCLOSURE CITATION Filing Date: Group Art Unit: February 1, 2000 Stacy Whitmore U.S. PATENT DOCUMENTS Examiner Sub-Initial **Patent Number Issue Date** Class Class Filing Date Name US 5,869,386 2/1999 Hamajima US 6,143,628 11/2000 Sato US 6,190,937 2/2001 Nakagawa US 6,140,209 10/2000 Iwane FOREIGN PATENT DOCUMENTS Examiner Sub-Initial **Patent Number Issue Date** Country Class Class Translation 1/29/93 Japan (w/ English Abstract) ☐ Yes ☐ No 5-021338 7-302889 11/14/95 Japan (w/ English Abstract) ☐ Yes ☐ No JPA10-326882 12/8/98 Japan ☐ Yes ☐ No ☐ Yes ☐ No OTHER DOCUMENTS (Including Author, Title, Date, etc.) English translation of Nagano et al., IEICE Technical Report, "Oxidized Porous Silicon and Its Application", Vol. 79, SSD79-9549 (1979) Imai et al., Journal of Crystal Growth, "Crystalline Quality of Silicon Layer Formed by FIPOS Technology", Vol. 63, 547 (1983) A. Uhlir, Bell System Technical Journal, "Electrolytic Shaping of Germanium and Silicon", Vol. 35, 333 T. Unagami, Journal of Electrochemical Society, "Formation Mechanism of Porous Silicon Layer by Anodization in HF Solution", Vol 127, 476 Nagano et al., IEICE Technical Report, "Oxidized Porous Silicon and It's Application", Vol. 79, SSD79-9549 (1979)K. Imai, Solid State Electronics, "A New Dielectric Isolation Method Using Porous Silicon", Vol. 24, 159

R.P. Holmstrom and Y.Y. Chi, "Complete Dielectric Isolation By Highly Selective and Self-Stopping

Date Considered

Formation of Oxidized Porous Silicon"

Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant.

Initial if reference considered, whether or not citation is in conformance with MPEP §609.

683140 v1

Examiner

EXAMINER:

	Number Filed	Number Extra	Rate	Basic Fee \$740.00/370.00
Total Claims	3- 20 =	0x	\$18.00/\$9.00	\$ 0
Independent Claims	3 - 3 =	0x	\$80.00/ \$40.00	\$ 0
Multiple Dependen	t Claims	If marked, add fee of \$2	70.00 (\$135.00)	\$ 0
			TOTAL:	\$ 740.00

	herewith
	\$
$\boxtimes$	A check in the amount of \$740.00 in payment of the application filing fees is attached.
	Charge fee to Deposit Account No. <u>13-4500</u> , Order No A DUPLICATE COPY OF THIS SHEET IS ATTACHED.
$\boxtimes$	The Commissioner is hereby authorized to charge any additional fees which may be required for filing this application pursuant to 37 CFR §1.16, including all extension of time fees pursuant to 37 C.F.R. § 1.17 for maintaining copendency with the parent
	application, or credit any overpayment to Deposit Account No. <u>13-4500</u> , Order No. <u>4610US1</u> . A DUPLICATE COPY OF THIS SHEET IS ATTACHED.

Respectfully submitted,

MORGAN & FINNEGAN, L.L.P.

Dated: February 21, 2002

Ву: ///////

Gerard E. Reinhardt Registration No. 43,041

Correspondence Address:

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